**TOSHIBA** 2GWJ42C

TOSHIBA SCHOTTKY BARRIER RECTIFIER SCHOTTKY BARRIER TYPE

## 2 G W J 4 2 C

HIGH SPEED RECTIFIER APPLICATIONS

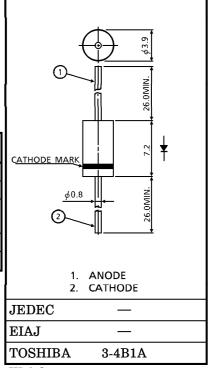
Unit in mm

Average Forward Current :  $I_{F(AV)} = 2.0A (Ta = 25^{\circ}C)$ 

 $: V_{FM} = 0.55V \text{ (Max.)}$ Low Forward Voltage

## MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC                  | SYMBOL              | RATING     | UNIT |  |
|---------------------------------|---------------------|------------|------|--|
| Repetitive Peak Reverse Voltage | $V_{RRM}$           | 40         | V    |  |
| Average Forward Current         | I <sub>F (AV)</sub> | 2.0        | A    |  |
| Peak One Cycle Surge Forward    | Inche               | 40 (50Hz)  | Δ    |  |
| Current (Non - Repetitive)      | I <sub>FSM</sub>    | 40 (30112) | A    |  |
| Junction Temperature            | $T_{j}$             | -40~125    | °C   |  |
| Storage Temperature Range       | $ m T_{stg}$        | -40~125    | °C   |  |

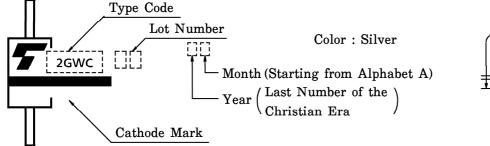


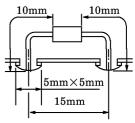
Weight: 0.47g

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC                  | SYMBOL                | TEST CONDITION                 | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|-----------------------|--------------------------------|------|------|------|------|
| Peak Forward Voltage            | $V_{	extbf{FM}}$      | $I_{\text{FM}} = 2.0 \text{A}$ | _    | _    | 0.55 | V    |
| Repetitive Peak Reverse Current | $I_{RRM}$             | $V_{RRM} = 40V$                | _    | _    | 0.5  | mA   |
| Junction Capacitance            | $C_{ m j}$            | $V_R = 10V$ , $f = 1MHz$       | _    | 125  | _    | рF   |
| Thermal Resistance (Note 1)     | R <sub>th (j-a)</sub> | Junction to Ambient            | _    | _    | 100  | °C/W |
| Thermal Resistance (Note 1)     | R <sub>th (j-l)</sub> | Junction to Lead               | _    | _    | 30   | °C/W |

## **MARKING** Note 1: THERMAL RESISTANCE





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